



Introduction

The D0188_VCSEL_8G high speed products are 850nm multimode Vertical Cavity Surface Emitting Laser (VCSEL) devices engineered to meet data communication rates up to 8 Gbps with low electrical parasitics and proven high reliability. The VCSEL devices have a circular low divergence beam that can be efficiently coupled into a 50/125 or $62.5/125\mu m$ multimode fiber. Singlet, 1x4, 1x8, or 1x12 arrays are all provided in common cathode configuration with 250 μm pitch between each channel.

Key Features

- 850nm multimode emission
- Low threshold and operation current
- Excellent reliability
- Data rates up to 8 Gb/s for singlet chip
- Optimized for -5C to 70C operation
- Customization for 1x4, 1x8 and 1x12 array configuration
- Highly robust 4" IC wafer FAB with fast cycle-time
- Deliverable in GCS Known Good Die[™] with 100% testing and inspection
- RoHS compliant

Applications

- 1/2/4/8 Gbps data communication
- Active Optical Cable
- USB 3.0
- HDMI



Dimensions

Attention: Avoid ESD; the device may be permanently damaged.

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SPECIFICATIONS						
	Symbol	Min.	Typical	Max.	Unit	Test Condition
Emission Wavelength	λ	840	850	860	nm	$I_{OP} = 6mA$
Threshold current	I _{th}	0.5	1	1.5	mA	$Temp = 25^{\circ}C$
Operating voltage	V _{OP}	1.8	1.9	2.2	V	$I_{OP} = 6mA$, Temp = 25°C
Slope efficiency	η_s	0.3	0.4	0.5	W/A	$Temp = 25^{\circ}C$
Differential resistance	R _d	45	60	75	Ω	Temp = 25° C, I _{OP} = 6mA
Optical output power	P _{OP}	1	1.5		mW	Temp = 25° C, I _{OP} = 6mA
Beam divergence (FWHM)	θ		20		deg	$I_{OP} = 6mA$
Spectral bandwidth (RMS)	$\Delta\lambda_{RMS}$		0.4	0.8	nm	Temp = 25° C, I _{OP} = 6mA
Rise and fall time	$t_{\rm R}/t_{\rm F~20/80}$		45	60	ps	$I_{OP} = 6mA$
Relative intensity noise	RIN		-128		dB/Hz	
Wavelength tuning over current			0.3		nm/mA	
Wavelength tuning over temp			0.07		nm/K	
Thermal impedance	Z _{Thermal}		2		°K/mW	

ABSOLUTE MAXIMUM RATING

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	Symbol	Min.	Typical	Max.	Unit
Optical output power	P _{max}			8	mW
Peak forward current	\mathbf{I}_{f}			16	mA
VCSEL reverse voltage	$V_{\rm rv}$			8	V
Operating temperature	T _{OP}	-40		85	°C
Storage Temperature	T _{st}			100	°C

UNIFORMITY OF ARRAY PRODUCTS

	Symbol	Min.	Typical	Max.	Unit
Threshold current	ΔI_{th}			0.15	mA
Slope efficiency	$\Delta\eta_s$			0.1	W/A
Series resistance	R _s			8	%

About GCS:

GCS is a world-class semiconductor manufacturer specializing in advanced photodiode technologies. We provide advanced GaAs and InGaAs photodiodes of varying data rate and application to multiple top tier optical transceiver customers throughout the world. With over 15 years' experience and over 150 million units delivered, our state of the art manufacturing facility has the capacity to produce 2,000 (100mm) wafers per month.

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